NSN 5980-01-363-1089

Light Emitting Diode - Page 1 of 1

AeroBase Group

View Online at https://aerobasegroup.com/nsn/5980-01-363-1089

Inclosure Material:

Metal

Mounting Facility Quantity:

1

Mounting Method:

Threaded stud

Overall Width Across Flats:

0.560 inches

Semiconductor Material:

Gallium phosphide

Voltage Rating In Volts Per Characteristic:

3.6 on-state voltage, dc and 6.0 on-state voltage, dc

Current Rating Per Characteristic:

14.00 milliamperes base current, instantaneous nanoamperes and 32.00 milliamperes forward current, total rms nanoamperes

Terminal Type And Quantity:

2 uninsulated wire lead

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

No

Fiig:

A110a0